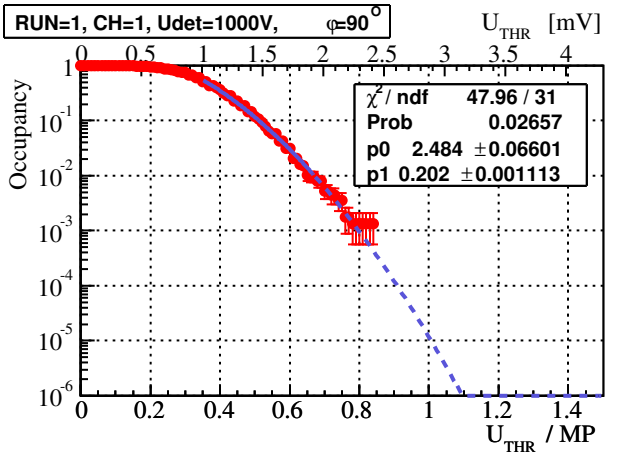
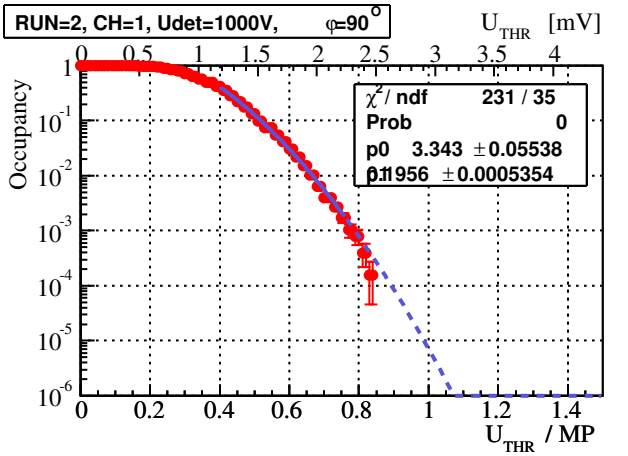
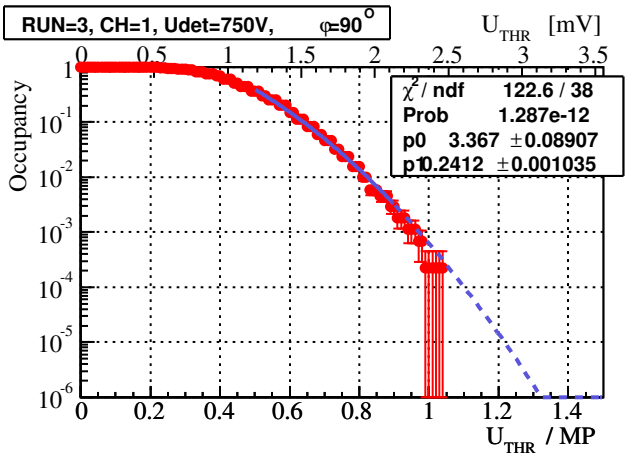
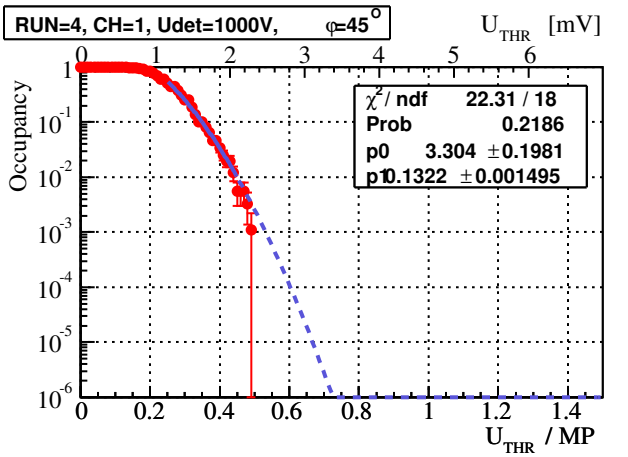
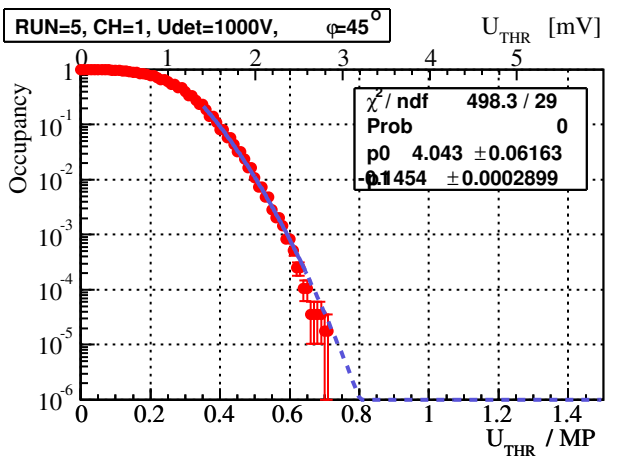
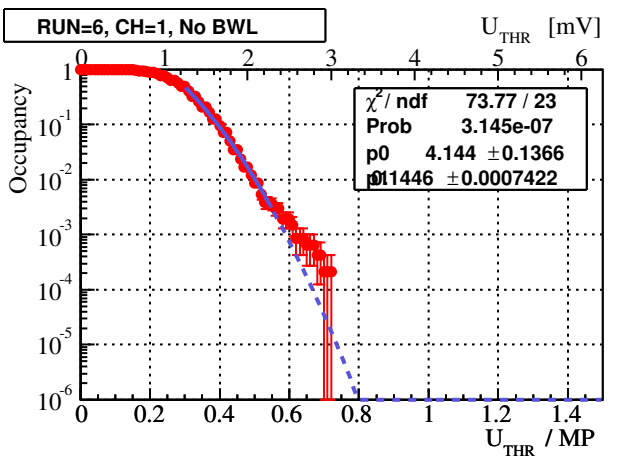

RUN=1, CH=1, Udet=1000V, φ=90°
U_THR [mV]
Occupancy
χ² / ndf 47.96 / 31
Prob 0.02657
p0 2.484 ±0.06601
p1 0.202 ±0.001113
U_THR / MP

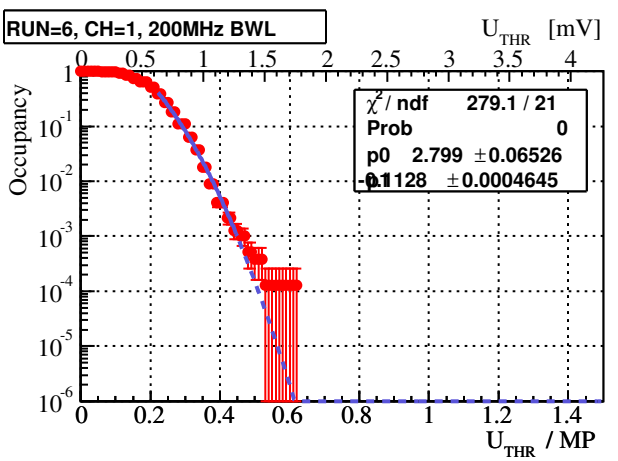

RUN=2, CH=1, Udet=1000V, φ=90°
U_THR [mV]
Occupancy
χ² / ndf 231 / 35
Prob 0
p0 3.343 ±0.05538
p1 0.1956 ±0.0005354
U_THR / MP


RUN=3, CH=1, Udet=750V, φ=90°
U_THR [mV]
Occupancy
χ² / ndf 122.6 / 38
Prob 1.287e-12
p0 3.367 ±0.08907
p1 0.2412 ±0.001035
U_THR / MP


RUN=4, CH=1, Udet=1000V, φ=45°
U_THR [mV]
Occupancy
χ² / ndf 22.31 / 18
Prob 0.2186
p0 3.304 ±0.1981
p1 0.1322 ±0.001495
U_THR / MP


RUN=5, CH=1, Udet=1000V, φ=45°
U_THR [mV]
Occupancy
χ² / ndf 498.3 / 29
Prob 0
p0 4.043 ±0.06163
p1 0.1454 ±0.0002899
U_THR / MP


RUN=6, CH=1, No BWL
U_THR [mV]
Occupancy
χ² / ndf 73.77 / 23
Prob 3.145e-07
p0 4.144 ±0.1366
p1 0.1446 ±0.0007422
U_THR / MP


RUN=6, CH=1, 200MHz BWL
U_THR [mV]
Occupancy
χ² / ndf 279.1 / 21
Prob 0
p0 2.799 ±0.06526
p1 0.1128 ±0.0004645
U_THR / MP